



Product Summary

BV _{DSS}	R bs(on) max	I _D T _A = +25°C
1001	$350m\Omega @ V_{GS} = -10V$	-2.4A
-100V	450mΩ @ V _{GS} = -6V	-2.1A

Description and Applications

This MOSFET has been designed to minimize the on-state resistance and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Motor controls
- DC-DC converters
- Power management functions
- Relay and solenoid driving

100V P-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- Fast Switching Speed
- Low Input Capacitance
- Low Gate Drive
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The ZXMP10A17GQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

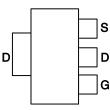
Mechanical Data

- Package: SOT223
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 (63)
- Weight: 0.112 grams (Approximate)

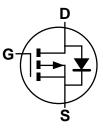
SOT223 (Type DN)



Top View



Pin Out - Top View



Equivalent Circuit

Ordering Information (Note 4)

Part Number	Baakaga	Packing		
	Package	Qty.	Carrier	
ZXMP10A17GQTA	SOT223 (Type DN)	1,000	Tape & Reel	
ZXMP10A17GQTC	SOT223 (Type DN)	4,000	Tape & Reel	

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information

SOT223 (Type DN)

ZXMP10A17 = Product Type Marking Code YWW = Date Code Marking Y = Year (ex: 2 = 2022) WW = Week (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage		V _{DSS}	-100	V	
Gate-Source Voltage		V _{GS}	±20	V	
		(Note 6)		-2.4	
Continuous Drain Current	$V_{GS} = -10V$	$T_A = +70^{\circ}C$ (Note 6)	ID	-1.9	А
		(Note 5)		-1.7	
Pulsed Drain Current	$V_{GS} = -10V$	(Note 7)	IDM	-9.4	А
Continuous Source Current	(Body Diode)	(Note 6)	ls	-2.4	А
Pulsed Source Current (Body Diode) (Note 7)		I _{SM}	-9.4	А	

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 5)		2.0 16	W mW/°C	
Linear Derating Factor	(Note 6)	P _D	3.9 31		
Thermal Resistance, Junction to Ambient	(Note 5)	D	62.5		
Thermai Resistance, Sunction to Ambient	(Note 6)	R _θ JA	32.0	°C/W	
Thermal Resistance, Junction to Case	(Note 5)	R _θ JC	7.7		
Operating and Storage Temperature Range		TJ, T _{STG}	-55 to +150	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test	Condition
OFF CHARACTERISTICS	0,				•		
Drain-Source Breakdown Voltage	BV _{DSS}	-100		_	V	I _D = -250μA, V _{GS} = 0V	
Zero Gate Voltage Drain Current	IDSS			-0.5	μA	V _{DS} = -100V, V	
Gate-Source Leakage	I _{GSS}			±100	nA	$V_{GS} = \pm 20V, V$	_{DS} = 0V
ON CHARACTERISTICS							
Gate Threshold Voltage	V _{GS(th)}	-2.0		-4.0	V	I _D = -250μA, V	_{DS} = V _{GS}
Static Drain-Source On-Resistance (Note 8)				0.350	Ω	$V_{GS} = -10V, I_{D}$	= -1.4A
Static Drain-Source On-Resistance (Note 8)	R _{DS(on)}	_		0.450	12	$V_{GS} = -6V, I_D =$	-1.2A
Forward Transconductance (Notes 8, 9)	g _{fs}	_	2.8	_	S	$V_{DS} = -15V, I_{D}$	= -1.4A
Diode Forward Voltage (Note 8)	V _{SD}	_	-0.85	-0.95	V	$I_{S} = -1.7A, V_{GS} = 0V$	
Reverse Recovery Time (Note 9)	t _{RR}		33	_	ns	I _F = -1.5A, di/dt = 100A/μs	
Reverse Recovery Charge (Note 9)	Q _{RR}		48		nC		
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	C _{iss}	_	424	_	pF	V _{DS} = -50V, V _{GS} = 0V f = 1MHz	
Output Capacitance	Coss	_	36.6	_	pF		
Reverse Transfer Capacitance	C _{rss}	_	29.8	_	pF		
Total Gate Charge (Note 10)	Qg	_	7.1	_	nC	$V_{GS} = -6.0V$	
Total Gate Charge (Note 10)	Qg	_	10.7	_	nC	$V_{GS} = -10V$ $V_{DS} = -50V$ $I_{D} = -1.4A$	
Gate-Source Charge (Note 10)	Q _{qs}	_	1.7	_	nC		
Gate-Drain Charge (Note 10)	Q _{gd}	_	3.8	_	nC		
Turn-On Delay Time (Note 10)	t _{D(on)}		3.0		ns	V _{DD} = -15V, V _{GS} = -10V I _D = -1A, R _G ≅ 6.0Ω	
Turn-On Rise Time (Note 10)	t _R	_	3.5	_	ns		
Turn-Off Delay Time (Note 10)	t _{D(off)}	_	13.4	_	ns		
Turn-Off Fall Time (Note 10)	t _F	_	7.2	_	ns		

5. For a device surface mounted on 25mm x 25mm x 1.6mm FR-4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is Notes: measured when operating in a steady-state condition.

6. Same as Note 5, except the device is measured at t \leq 10 seconds.

7. Same as Note 5, except the device is pulsed with D = 0.02 and pulse width 300 µs. The pulse current is limited by the maximum junction temperature.

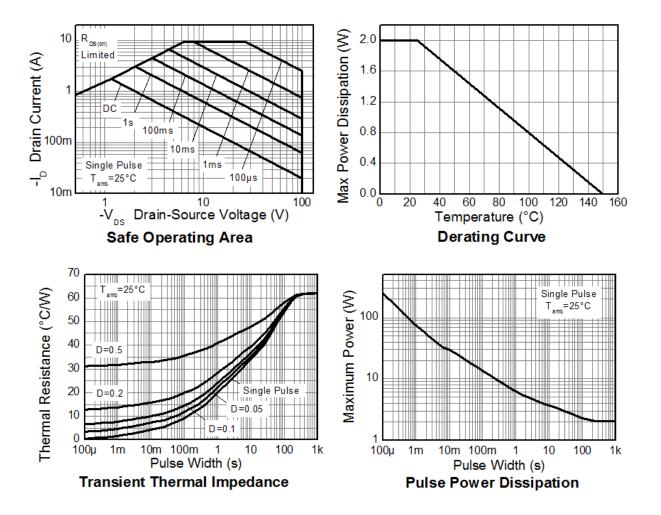
8. Measured under pulsed conditions. Pulse width \leq 300µs; duty cycle \leq 2%.

9. For design aid only, not subject to production testing.
10. Switching characteristics are independent of operating junction temperatures.

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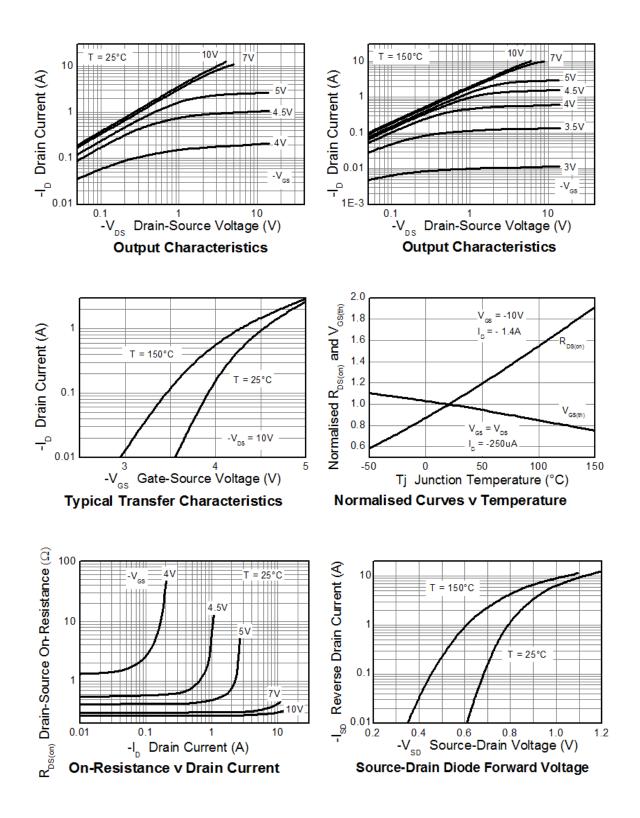


Thermal Characteristics





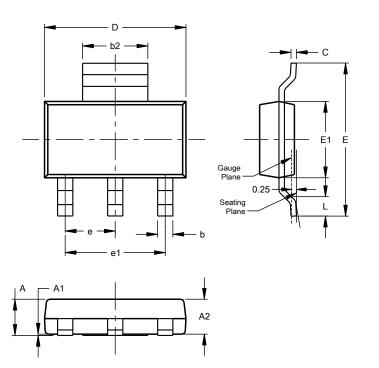
Typical Characteristics (continued)





Package Outline Dimensions

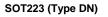
Please see http://www.diodes.com/package-outlines.html for the latest version.



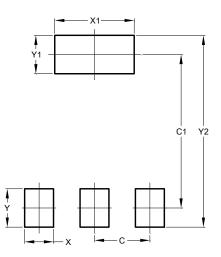
SOT223 (Type DN)					
Dim	Min	Min Max			
Α		1.70			
A1	0.01	0.15			
A2	1.50	1.68	1.60		
b	0.60	0.80	0.70		
b2	2.90	3.10 -			
С	0.20	0.32			
D	6.30	6.70			
E	6.70	7.30			
E1	3.30	3.70			
е			2.30		
e1			4.60		
L	0.85				
All [All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT223 (Type DN)



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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